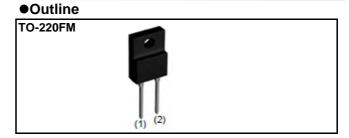
SCS320AM

SiC Schottky Barrier Diode

Datasheet

V_R	650V
I _F	20A
Q_{C}	47nC



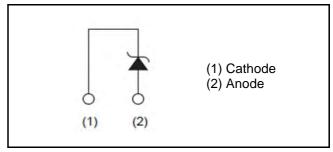
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

Applications

- PFC Boost Topology
- · Secondary Side Rectification
- Data Center
- PV Power Conditioners

•Inner circuit



Packaging specifications

		Packaging	Tube	
		Reel size (mm)	-	
Туре	Tape width (mm)	-		
	Basic ordering unit (pcs)	50		
		Packing code	С	
		Marking	SCS320AM	

● Absolute maximum ratings (T_i = 25°C)

	Parameter	Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (De	C)	V _R	650	V
Continuous forward	current (T _c = 40°C)	I _F	20	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		123	А
repetitive forward PW=10ms sinusoidal, T _j =150°C		I _{FSM}	104	А
current	PW=10μs square, T _j =25°C		450	А
Repetitive peak forward current		I _{FRM}	46 *1	А
1≦PW≦10ms, T _j =25°C		$\int i^2 dt$	75	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J 1⁻at	54	A ² s
Total power disspation		P_{D}	41 * ²	W
Junction temperature		T_j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

ullet Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values		Unit	
			Min.	Тур.	Max.	Offic
DC blocking voltage	V_{DC}	I _R =100μA	650	-	-	V
		I _F =20A,T _j =25°C	-	1.35	1.50	V
Forward voltage	V_{F}	I _F =20A,T _j =150°C	-	1.44	1.71	V
		I _F =20A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.06	100	μΑ
		V _R =650V,T _j =150°C	-	4	400	μΑ
		V _R =650V,T _j =175°C	-	12	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	1000	-	pF
		V _R =650V,f=1MHz	-	91	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	47	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	25	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	220	-	mJ

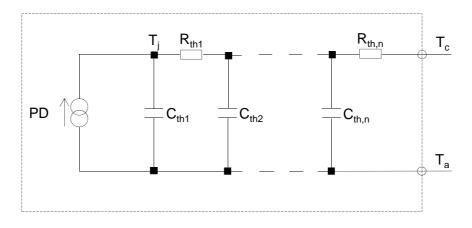
Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol		Min.	Тур.	Max.	Offic
Thermal resistance	$R_{th(j-c)}$	-	-	3.1	3.6	°C/W

●Typical Transient Thermal Characteristics

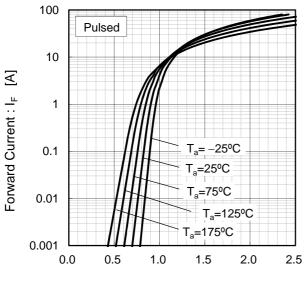
Symbol	Value	Unit
R _{th1}	1.26E-01	
R _{th2}	7.51E-01	K/W
R _{th3}	2.17E+00	

Symbol	Value	Unit
C_{th1}	7.42E-04	
C_{th2}	5.97E-03	Ws/K
C _{th3}	4.40E-01	



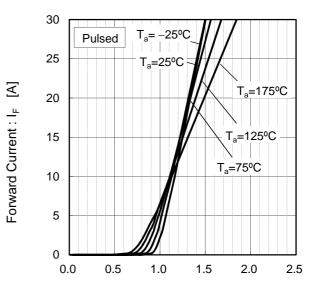
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



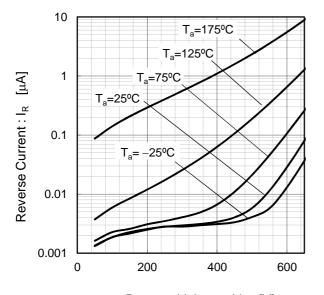
Forward Voltage: V_F [V]

Fig.2 V_F - I_F Characteristics



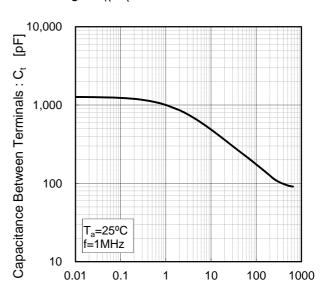
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage: V_R [V]

•Electrical characteristic curves

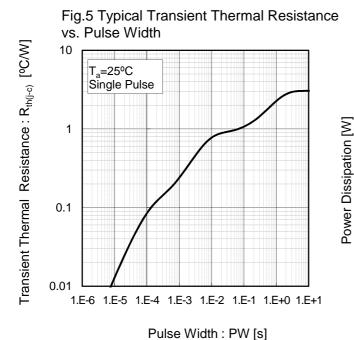
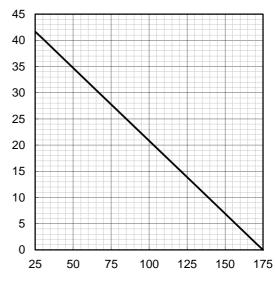
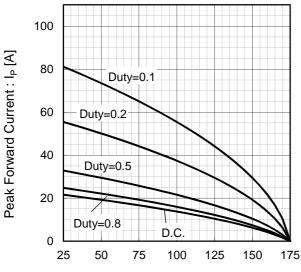


Fig.6 Power Dissipation



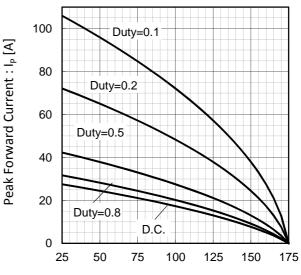
Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c



Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

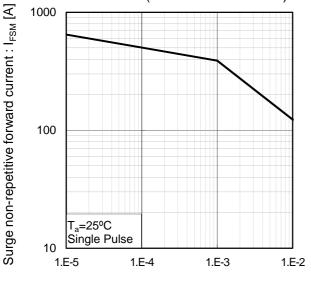
Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



 $\label{eq:case_to_case_to_case_to_case} \begin{array}{l} \text{Case Temperature}: T_c \ [^{\circ}\text{C}] \\ \text{*4 Based on typ Vf, typ R}_{\text{th(j-c)}} \\ \text{Typical value, not guaranteed} \\ \text{Valid for switching of above 10kHz, excluding D.C. curve} \end{array}$

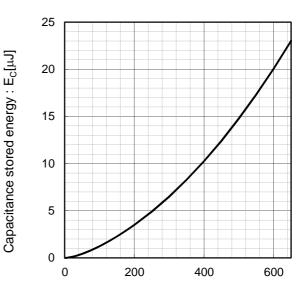
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

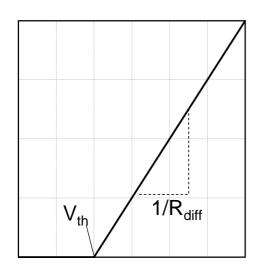
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.66E-01	V
a ₁	-1.10E-03	V/°C
b ₀	1.76E-02	Ω
b ₁	3.73E-05	Ω/°C
b ₂	3.84E-07	Ω /°C ²

 $T_i \text{ in } {}^{\circ}\text{C}; -55 {}^{\circ}\text{C} < T_i < 175 {}^{\circ}\text{C}; I_F < 40 \text{ A}$

Forward Current: IF

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SCS320AM - Web Page

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